COMPLIANT



Vishay High Power Products

Passivated Assembled Circuit Elements, 25 A



PACE-PAK (D-19)

PRODUCT SUMMARY	
Io	25 A

FEATURES

- · Glass passivated junctions for greater reliability
- Electrically isolated base plate
- Available up to 1200 V_{RRM}/V_{DRM}
- High dynamic characteristics
- Wide choice of circuit configurations
- Simplified mechanical design and assembly
- UL E78996 approved
- Compliant to RoHS directive 2002/95/EC

DESCRIPTION

The P100 series of integrated power circuits consists of power thyristors and power diodes configured in a single package. With its isolating base plate, mechanical designs are greatly simplified giving advantages of cost reduction and reduced size.

Applications include power supplies, control circuits and battery chargers.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
lo	85 °C	25	A		
I _{TSM} ,	50 Hz	357	A		
I _{FSM}	60 Hz	375	A		
l ² t	50 Hz	637	A2-		
	60 Hz	580	A ² s		
$I^2\sqrt{t}$		6365	A ² √s		
V _{RRM}	Range	400 to 1200	V		
V _{ISOL}		2500	V		
T _J		40 to 105	°C		
T _{Stg}		- 40 to 125	C		

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS					
TYPE NUMBER	V _{RRM} /V _{DRM} , MAXIMUM REPETITIVE PEAK REVERSE AND PEAK OFF-STATE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} MAXIMUM AT T _J MAXIMUM mA		
P101, P121, P131	400	500			
P102, P122, P132	600	700			
P103, P123, P133	800	900	10		
P104, P124, P134	1000	1100			
P105, P125, P135	1200	1300			

P100 Series

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ON-STATE CONDUCTIO	N					
PARAMETER	SYMBOL		TEST CONDITIONS		VALUES	UNITS
Maximum DC output current	ı	Full bridge			25	Α
at case temperature	I _O	Full bridge			85	°C
		t = 10 ms	No voltage		357	
Maximum peak, one-cycle	I _{TSM} ,	t = 8.3 ms	reapplied		375	۸
non-repetitive on-state or forward current	I _{FSM}	t = 10 ms	100 % V _{RRM}		300	А
		t = 8.3 ms	reapplied	Sinusoidal half wave,	315	
		t = 10 ms	= 8.3 ms reapplied reapplied	initial T _J = T _J maximum	637	A ² s
Maximum I ² t for fusing	l ² t	t = 8.3 ms			580	
waximum i=t for fusing	1-1	t = 10 ms			450	
		t = 8.3 ms			410	
Maximum I ² √t for fusing	I ² √t	$t=0.1$ ms to 10 ms, no voltage reapplied I^2t for time $tx=I^2\sqrt{t}\cdot\sqrt{t}x$		6365	A²√s	
Maximum value of threshold voltage	V _{T(TO)}	T _J = 125 °C		0.82	V	
Maximum level value of on-state slope resistance	r _{t1}	$T_J = 125$ °C, average power = $V_{T(TO)} \times I_{T(AV)} + r_t + (I_{T(RMS)})^2$		12	mΩ	
Maximum on-state voltage drop	V_{TM}	$I_{TM} = \pi \times I_{T(AV)}$		1.35	V	
Maximum forward voltage drop	V_{FM}	$I_{FM} = \pi \times I_{F(AV)}$ $T_{J} = 25 \text{ °C}$		1.00	V	
Maximum non-repetitive rate of rise of turned-on current	dl/dt	$T_{J} = 125 ^{\circ}\text{C} \text{ from } 0.67 V_{DRM}$ $I_{TM} = \pi x I_{T(AV)}, I_{g} = 500 \text{mA}, t_{r} < 0.5 \mu\text{s}, t_{p} > 6 \mu\text{s}$		200	A/µs	
Maximum holding current	I _H	T _J = 25 °C anode supply = 6 V, resistive load, gate open		130	mA	
Maximum latching current	l _L	T _J = 25 °C anode supply = 6 V, resistive load		250	IIIA	

BLOCKING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum critical rate of rise of off-state voltage	dV/dt	T _J = 125 °C, exponential to 0.67 V _{DRM} gate open	200	V/µs
Maximum peak reverse and off-state leakage current at V _{RRM} , V _{DRM}	I _{RRM} , I _{DRM}	T _J = 125 °C, gate open circuit	10	mA
Maximum peak reverse leakage current	I _{RRM}	T _J = 25 °C	100	μΑ
RMS isolation voltage	V _{ISOL}	50 Hz, circuit to base, all terminals shorted, $T_J = 25 ^{\circ}\text{C}$, $t = 1 \text{s}$	2500	V



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TRIGGERING					
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS
Maximum peak gate power	P _{GM}			8	W
Maximum average gate power	P _{G(AV)}			2	VV
Maximum peak gate current	I _{GM}			2	Α
Maximum peak negative gate voltage	-V _{GM}			10	V
		T _J = - 40 °C	Anode supply =	3	V
Maximum gate voltage required to trigger	V_{GT}	T _J = 25 °C		2	
		T _J = 125 °C		1	
		T _J = - 40 °C	6 V resistive load	90	
Maximum gate current required to trigger	I _{GT}	T _J = 25 °C		60	mA
		T _J = 125 °C		35	
Maximum gate voltage that will not trigger	V_{GD}	$T_J = 125 ^{\circ}\text{C}$, rated V_{DRM} applied 0.2		0.2	V
Maximum gate current that will not trigger	I_{GD}			mA	

THERMAL AND MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction operating and storage temperature range	T _J , T _{Stg}		- 40 to 125	°C
Maximum thermal resistance, junction to case per junction	R _{thJC}	DC operation	2.24	K/W
Maximum thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth and greased	0.10	R/ VV
Mounting torque, base to heatsink (1)			4	Nm
Approximate weight			58	g
Approximate weight			2.0	OZ.

Note

⁽¹⁾ A mounting compund is recommended and the torque should be checked after a period of 3 hours to allow for the spread of the compound

CIRCUIT TYPE AND CODING (1)						
	CIRCUIT "0"	CIRCUIT "2"	CIRCUIT "3"			
Terminal positions	AC2 G2 +	AC1 G1 - AC2 G2 +	AC2 G2 - —G1 G4 — AC1 G3 +			
Schematic diagram	AC20 (+)	G1 9 G2 AC20 AC10 (-) (+)	G3 9 G1 AC10 AC20 G4 G2 (+)			
	Single phase hybrid bridge common cathode	Single phase hybrid bridge doubler	Single phase all SCR bridge			
Basic series	P10.	P12.	P13.			
With voltage suppression	P10.K	P12.K	P13.K			
With freewheeling diode	P10.W	-	-			
With both voltage suppression and freewheeling diode	P10.KW	-	-			

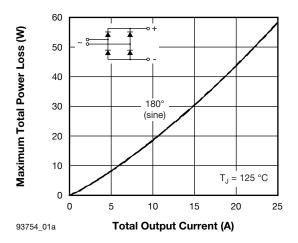
Note

⁽¹⁾ To complete code refer to Voltage Ratings table, i.e.: For 600 V P10.W complete code is P102W

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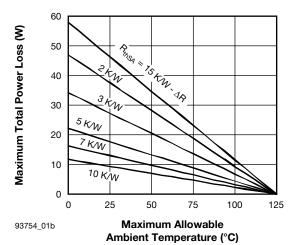


Fig. 1 - Current Ratings Nomogram (1 Module Per Heatsink)

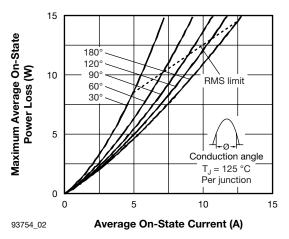


Fig. 2 - On-State Power Loss Characteristics

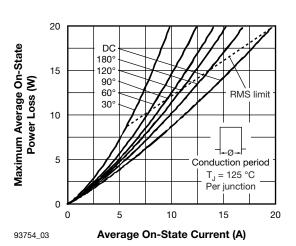


Fig. 3 - On-State Power Loss Characteristics

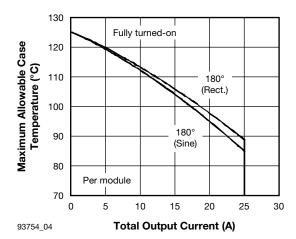


Fig. 4 - Current Ratings Characteristics

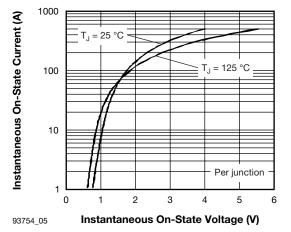


Fig. 5 - On-State Voltage Drop Characteristics



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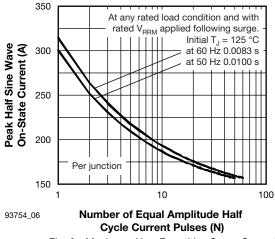


Fig. 6 - Maximum Non-Repetitive Surge Current

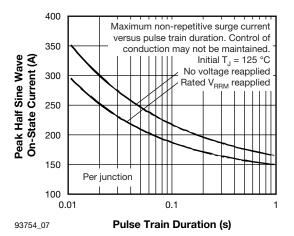


Fig. 7 - Maximum Non-Repetitive Surge Current

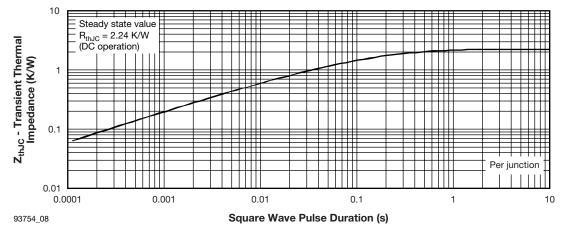


Fig. 8 - Thermal Impedance Z_{thJC} Characteristics

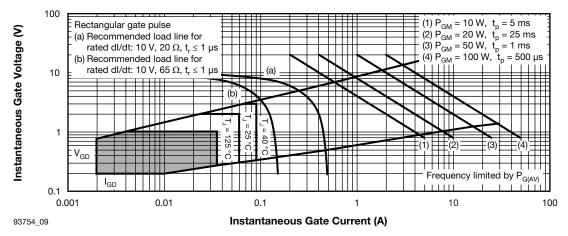


Fig. 9 - Gate Characteristics

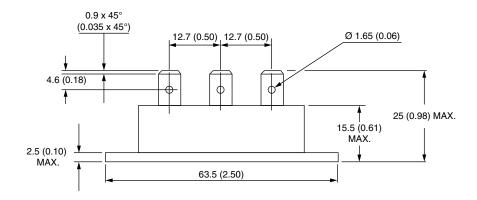
LINKS TO RELATED DOCUMENTS			
Dimensions	www.vishay.com/doc?95335		

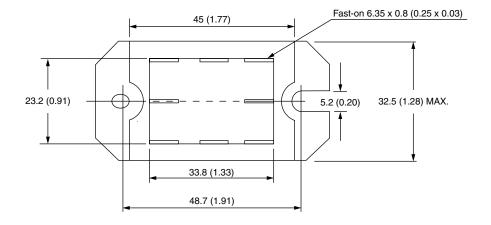


Vishay Semiconductors

D-19 PACE-PAK

DIMENSIONS in millimeters (inches)





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